



#### P-CHANNEL ENHANCEMENT MODE MOSFET

#### **Product Summary**

BV <sub>DSS</sub>	R <sub>DS(ON)</sub> Max	I <sub>D</sub> Max T <sub>A</sub> = +25°C (t<10s)
	7.0mΩ @ V <sub>GS</sub> = -10V	-17A
-30V	10.0mΩ @ V <sub>GS</sub> = -4.5V	-13A

#### **Features and Benefits**

- Low On-Resistance
- Low Input Capacitance
- Fast Switching Speed
- ESD Protected Gate
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)

#### **Description and Applications**

This MOSFET is designed to minimize the on-state resistance (R<sub>DS(ON)</sub>) yet maintain superior switching performance, making it ideal for high efficiency power management applications.

- Backlighting
- Power Management Functions
- DC-DC Converters

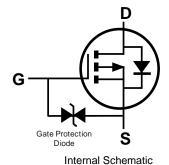
#### **Mechanical Data**

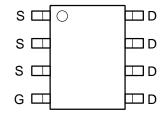
- Case: SO-8
- Case Material: Molded Plastic, "Green" Molding Compound.
   UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 3 per J-STD-020
- Terminal Connections Indicator: See Diagram Below
- Terminals: Finish—Matte Tin Annealed Over Copper Leadframe. Solderable per MIL-STD-202, Method 208 @3
- Weight: 0.074 grams (Approximate)





Top View





Top View Pin Configuration

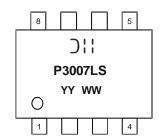
#### **Ordering Information** (Note 4)

Part Number	Case	Packaging
DMP3007LSS-13	SO-8	2,500/Tape & Reel

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
- See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

## **Marking Information**



⟩¦¦ = Manufacturer's Marking
P3007LS = Product Type Marking Code
YYWW = Date Code Marking
YY or YY= Year (ex: 18 = 2018)
WW = Week (01 to 53)



### Maximum Ratings (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit				
Drain-Source Voltage			$V_{DSS}$	-30	V		
Gate-Source Voltage			$V_{GSS}$	±25	V		
Continuous Drain Current V 40V/Note 6V	Steady State	$T_A = +25^{\circ}C$ $T_A = +70^{\circ}C$	_	-14 -11.5	А		
Continuous Drain Current, V <sub>GS</sub> = 10V (Note 6)	t<10s	$T_A = +25$ °C $T_A = +70$ °C	I <sub>D</sub>	-17 -12.5	А		
Maximum Continuous Body Diode Forward Curren	Is	-16.5	Α				
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%)			I <sub>DM</sub>	-120	Α		
Pulsed Body Diode Forward Current (10µs Pulse, Duty Cycle = 1%)			ulsed Body Diode Forward Current (10µs Pulse, Duty Cycle = 1%)		I <sub>SM</sub>	-120	Α
Avalanche Current, L=1mH (Note 7)			I <sub>AS</sub>	-13	Α		
Avalanche Energy, L=1mH (Note 7)			E <sub>AS</sub>	87	mJ		

#### **Thermal Characteristics**

Characteristic		Symbol	Value	Unit
Total Power Dissipation (Note 5)	$T_A = +25^{\circ}C$	$P_{D}$	1.4	W
Thermal Resistance, Junction to Ambient (Note 5)	Steady State	В	91	°C/W
Thermal Resistance, Junction to Ambient (Note 5)	t<10s	$R_{\Theta JA}$	51	°C/W
Total Power Dissipation (Note 6)	$T_A = +25^{\circ}C$	$P_{D}$	2.1	W
Thermal Resistance, Junction to Ambient (Note 6)	Steady State	D	59	°C/W
Thermal Resistance, Junction to Ambient (Note 0)	t<10s	$R_{\Theta JA}$	48	°C/W
Thermal Resistance, Junction to Case (Note 6)		$R_{\Theta JC}$	9	°C/W
Operating and Storage Temperature Range		$T_{J,}T_{STG}$	-55 to +150	°C

## **Electrical Characteristics** ( $T_A = +25$ °C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 8)							
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	-30		_	V	$V_{GS} = 0V, I_D = -250\mu A$	
Zero Gate Voltage Drain Current	I <sub>DSS</sub>		_	-1	μΑ	$V_{DS} = -24V, V_{GS} = 0V$	
Gate-Source Leakage	I <sub>GSS</sub>		_	±10	μΑ	$V_{GS} = \pm 20V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 8)				•	•	•	
Gate Threshold Voltage	V <sub>GS(TH)</sub>	-1.0	_	-2.8	V	$V_{DS} = V_{GS}, I_{D} = -250 \mu A$	
		_	4.1	7	10 mΩ	$V_{GS} = -10V, I_D = -17A$	
Static Drain-Source On-Resistance	R <sub>DS(ON)</sub>	_	5.9	10		V <sub>GS</sub> = -4.5V, I <sub>D</sub> = -15A	
		_	6.4	12		V <sub>GS</sub> = -4.0V, I <sub>D</sub> = -13A	
Diode Forward Voltage	$V_{SD}$		-0.7	-1.2	V	$V_{GS} = 0V, I_{S} = -1A$	
DYNAMIC CHARACTERISTICS (Note 9)							
Input Capacitance	C <sub>iss</sub>	_	2826	_	pF	4514.14	
Output Capacitance	Coss	_	606	_	pF	$V_{DS} = -15V, V_{GS} = 0V,$ f = 1.0MHz	
Reverse Transfer Capacitance	C <sub>rss</sub>		305	_	pF	- I = 1.0WH2	
Gate Resistance	Rg		22.8	_	Ω	$V_{DS} = 0V, V_{GS} = 0V, f = 1.0MHz$	
Total Gate Charge (V <sub>GS</sub> = -4.5V)	Qg		31.2	_	nC		
Total Gate Charge (V <sub>GS</sub> = -10V)	Qg		64.2	_	nC	1,, 45,, 44,54	
Gate-Source Charge	$Q_{gs}$		10.6	_	nC	$V_{DS} = -15V, I_{D} = -11.5A$	
Gate-Drain Charge	$Q_{gd}$		11.6	_	nC	1	
Turn-On Delay Time	t <sub>D(ON)</sub>		4.8	_	ns		
Turn-On Rise Time	t <sub>R</sub>		4.3	_	ns	$V_{DD} = -15V, V_{GS} = -10V,$	
Turn-Off Delay Time	t <sub>D(OFF)</sub>	_	306	_	ns	$R_q = 6\Omega, I_D = -11.5A$	
Turn-Off Fall Time	t <sub>F</sub>	_	125	_	ns	1 -	
Reverse Recovery Time	t <sub>RR</sub>	_	19	_	ns		
Reverse Recovery Charge	Q <sub>RR</sub>	_	9.8	_	nC	$I_S = -11.5A$ , di/dt = 100A/ $\mu$ s	

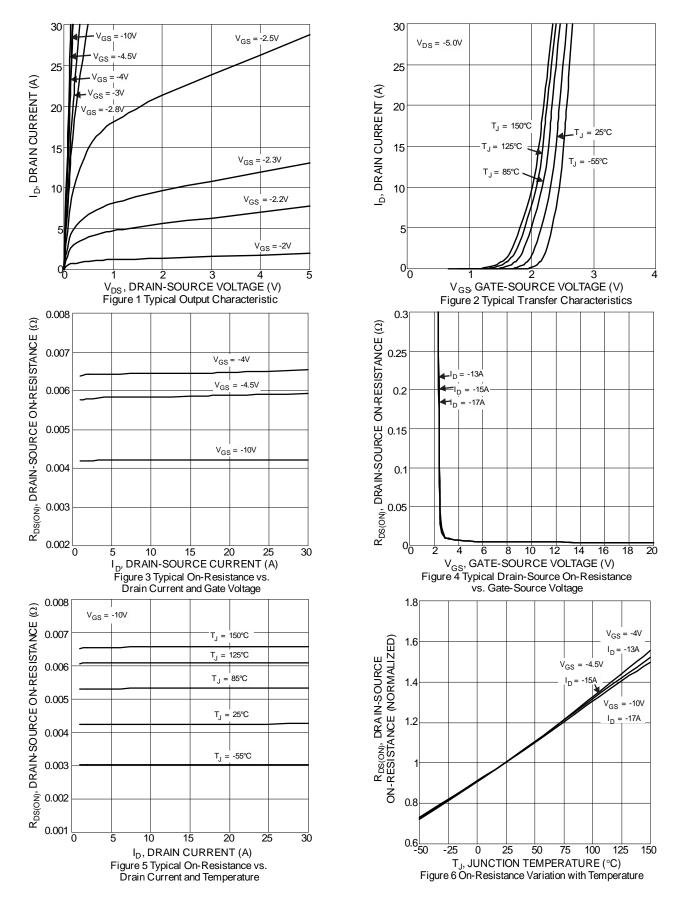
Notes: 5. Device mounted on FR-4 PC board, with minimum recommended pad layout, single sided.

<sup>6.</sup> Device mounted on FR-4 substrate PC board, 2oz copper, with thermal bias to bottom layer 1inch square copper plate.

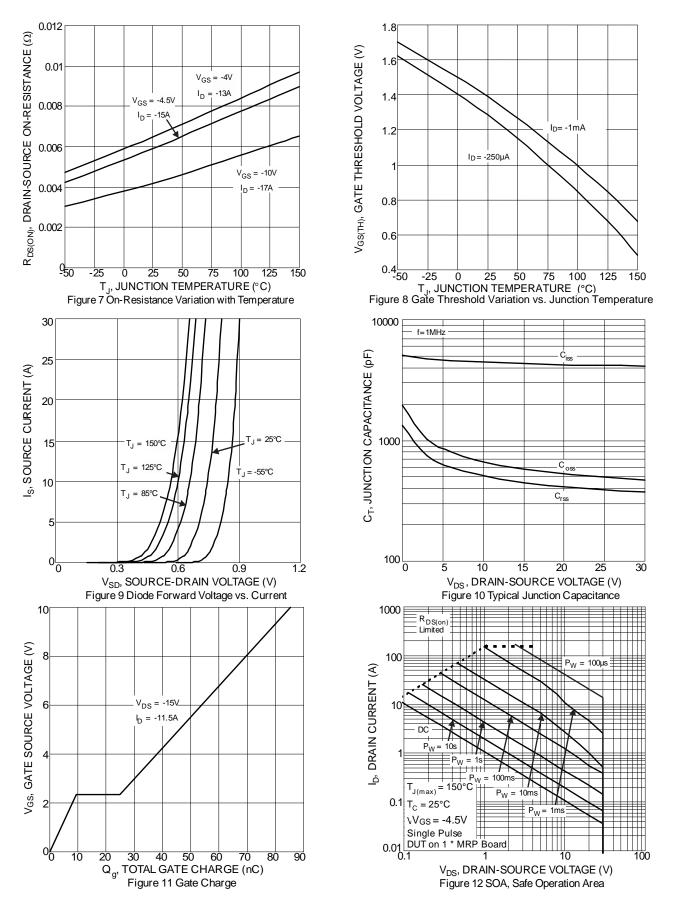
<sup>7.</sup>  $I_{AS}$  and  $E_{AS}$  ratings are based on low frequency and duty cycles to keep  $T_J$  = +25°C.

Short duration pulse test used to minimize self-heating effect.
 Guaranteed by design. Not subject to product testing.

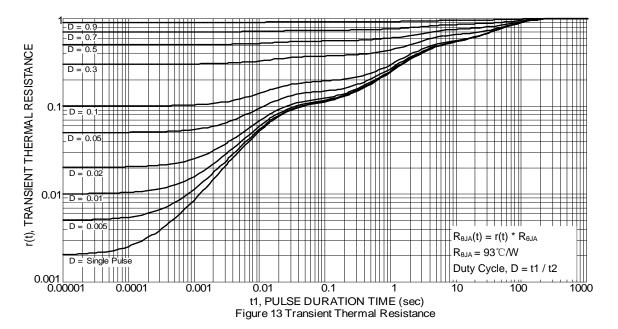








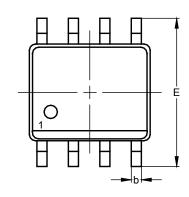


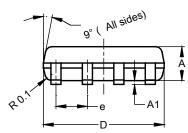


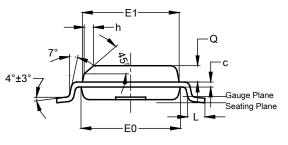


### **Package Outline Dimensions**

Please see http://www.diodes.com/package-outlines.html for the latest version.





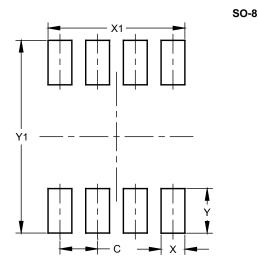


SO-8

SO-8						
Dim	Min	Max	Тур			
Α	1.40	1.50	1.45			
<b>A</b> 1	0.10	0.20	0.15			
q	0.30	0.50	0.40			
C	0.15	0.25	0.20			
D	4.85	4.95	4.90			
Ε	5.90	6.10	6.00			
E1	3.80	3.90	3.85			
E0	3.85	3.95	3.90			
е	_		1.27			
h			0.35			
٦	0.62	0.82	0.72			
Ø	0.60	0.70	0.65			
All Dimensions in mm						

## **Suggested Pad Layout**

Please see http://www.diodes.com/package-outlines.html for the latest version.



Dimensions	Value (in mm)
С	1.27
Х	0.802
X1	4.612
Y	1.505
V1	6.50



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